## DESCRIPTION

The RV1S2285A is an optically coupled isolator containing GaAs light emitting diodes and an NPN silicon phototransistor.
This package is very small and thin with long creepage distance $(8.2 \mathrm{~mm})$.
This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

## FEATURES

- Small and long creepage ( 8.2 mm , LSSOP)
- AC input response
- Operating ambient temperature: $115^{\circ} \mathrm{C}$
- High isolation voltage ( $\mathrm{BV}=5000 \mathrm{Vr} . \mathrm{m} . \mathrm{s}$.)
- Embossed tape product : RV1S2285ACCSP-10Yx\#KC0 : $3500 \mathrm{pcs} /$ reel
- Pb-Free product
- Safety standard
- UL : UL1577, Double protection
- CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation
- VDE : DIN EN 60747-5-5 (Option)



## APPLICATIONS

- Robot controller
- Industrial inverter
- AC Servo
- Programmable logic controller
- Measurement equipment
- Power supply

PACKAGE DIMENSIONS (UNIT : mm)


Weight : 0.075 g (Typ.)

## PHOTOCOUPLER CONSTRUCTIONS

| Parameter | UNIT (MIN.) |
| :--- | :---: |
| Air Distance | 8.2 mm |
| Creepage Distance | 8.2 mm |
| Isolation Distance | 0.15 mm |

## MARKING EXAMPLE



| R |  |  | An initial of "Renesas" |
| :---: | :---: | :---: | :---: |
| 2285 |  |  | Product Part Number* |
| $\bigcirc$ |  |  | No. 1 pin Mark |
| N744 | N |  | Rank Code |
|  | 744 |  | Assembly Lot |
|  |  | 7 | Last one-digit of Assembly Year |
|  |  | 44 | Weekly Serial Code |

* ) Applicable type numbers listed below

$$
\text { RV1S } 2285 \text { ACCSP-10Yx }
$$

Marking type number." RV1S" and "ACCSP-10Yx"" are omitted from original type number

ORDERING INFORMATION

| Part Number | Order Number | Solder Plating Specification* ${ }^{*}$ | Packing Style | Safety Standard Approval | Application Part Number* ${ }^{*}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { RV1S2285ACCSP } \\ & \text {-10YC } \end{aligned}$ | RV1S2285ACCSP <br> -10YC\#SC0 | Pb-Free and Halogen Free (Ni/Pd/Au) | $20 \mathrm{pcs}($ Tape $20 \mathrm{pcs} \mathrm{cut)}$ | Standard products (UL, CSA approved) | RV1S2285A |
|  | RV1S2285ACCSP -10YC\#KC0 |  | Embossed Tape 3500 pcs/reel |  |  |
| $\begin{aligned} & \text { RV1S2285ACCSP } \\ & -10 \mathrm{YV} \end{aligned}$ | RV1S2285ACCSP -10YV\#SC0 |  | 20 pcs (Tape 20 pcs cut) | UL, CSA, DIN EN 60747-5-5 approved |  |
|  | RV1S2285ACCSP <br> -10YV\#KC0 |  | Embossed Tape 3500 pcs/reel |  |  |

Notes:*1. When specifying CTR rank, please add "/CTR rank" after Order Number.
ex. L rank: RV1S2285ACCSP-10YC\#SC0/L
Notes:*2. For the application of the Safety Standard, following part number should be used.

## ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| Parameter |  | Symbol | Ratings | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Diode | Forward Current (DC) | $\mathrm{I}_{\mathrm{F}}$ | $\pm 30$ | mA |
|  | Power Dissipation Derating*1 | $\triangle \mathrm{PD}^{\prime}{ }^{\circ} \mathrm{C}$ | 0.6 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  | Power Dissipation | $\mathrm{PD}_{\mathrm{D}}$ | 60 | mW |
|  | Peak Forward Current ${ }^{*}$ | Ifp | $\pm 0.5$ | A |
| Transistor | Collector to Emitter Voltage | Vceo | 80 | V |
|  | Emitter to Collector Voltage | $V_{\text {ECo }}$ | 5 | V |
|  | Collector Current | Ic | 30 | mA |
|  | Power Dissipation Derating*1 | $\triangle \mathrm{Pc} /{ }^{\circ} \mathrm{C}$ | 1.2 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
|  | Power Dissipation | Pc | 120 | mW |
| Isolation Voltage ${ }^{* 3}$ |  | BV | 5000 | Vr.m.s. |
| Operating Ambient Temperature |  | TA | -40~+115 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature |  | $\mathrm{T}_{\text {stg }}$ | -40~+125 | ${ }^{\circ} \mathrm{C}$ |

*1 Derating from $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
*2 PW = $100 \mu \mathrm{~s}$, Duty Cycle = 1\%
*3 AC voltage for 1 minute at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{RH}=60 \%$ between input and output.
Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS $\left(T_{A}=25^{\circ} \mathrm{C}\right)$

| Parameter |  | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Diode | Forward Voltage | $V_{F}$ | $\mathrm{IF}_{\mathrm{F}}= \pm 5 \mathrm{~mA}$ |  | 1.15 | 1.4 | V |
|  | Terminal Capacitance | $\mathrm{C}_{\mathrm{t}}$ | $\mathrm{V}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 20 |  | pF |
| Transistor | Collector to Emitter Dark Current | $\mathrm{I}_{\text {ceo }}$ | $\mathrm{I}_{\mathrm{F}}=0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=80 \mathrm{~V}$ |  |  | 100 | nA |
| Coupled | Current Transfer Ratio (IC/IF)* ${ }^{*}$ | CTR | $\mathrm{IF}_{\mathrm{F}}= \pm 5 \mathrm{~mA}, \mathrm{~V}_{\text {CE }}=5 \mathrm{~V}$ | 50 | 200 | 400 | \% |
|  | CTR1/CTR2 ${ }^{\text {注 } 2}$ | CTR1/CTR2 | $\mathrm{I}_{\mathrm{F}}= \pm 5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | 0.3 | 1.0 | 3.0 |  |
|  | Collector Saturation Voltage | $\mathrm{V}_{\text {CE ( } \text { (at) }}$ | $\mathrm{I}_{\mathrm{F}}= \pm 10 \mathrm{~mA}, \mathrm{Ic}_{\mathrm{C}}=2 \mathrm{~mA}$ |  |  | 0.3 | V |
|  | Isolation Resistance | $\mathrm{R}_{1-\mathrm{O}}$ | $\mathrm{V}_{\text {I-O }}=1 \mathrm{k} \mathrm{V}_{\text {DC }}$ | $10^{11}$ |  |  | $\Omega$ |
|  | Isolation Capacitance | $\mathrm{ClO}_{\text {- }}$ | $\mathrm{V}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 0.4 |  | pF |
|  | Rise Time ${ }^{*}$ | $\mathrm{tr}_{r}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{I} \mathrm{I}=2 \mathrm{~mA}, \\ & \mathrm{R}_{\mathrm{L}}=100 \Omega \end{aligned}$ |  | 4 |  | $\mu \mathrm{s}$ |
|  | Fall Time ${ }^{* 3}$ | $\mathrm{t}_{\mathrm{f}}$ |  |  | 5 |  |  |

## *1. CTR rank

| CTR rank | CTR(\%) | Condition |
| :---: | :--- | :---: |
|  | $50 \sim 400$ | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
|  | $10 \sim$ | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
| M | $50 \sim 150$ | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
|  | $10 \sim$ | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
| L | $100 \sim 300$ | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
|  | $20 \sim$ | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{C E}=5 \mathrm{~V}$ |
| K | $150 \sim 350$ | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ |
|  | $20 \sim$ | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, V_{C E}=5 \mathrm{~V}$ |

*2. $\mathrm{CTR} 1=\mathrm{IC}_{1} / \mathrm{IF}_{\mathrm{F}}, \mathrm{CTR} 2=\mathrm{I} \mathrm{I} 2 / \mathrm{I}_{\mathrm{F} 2}$

*3. Test circuit for switching time


TYPICAL CHARACTERISTICS (TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)


FORWARD CURRENT vs


COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE


TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE


COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE


Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS (TA $=+25^{\circ} \mathrm{C}$, unless otherwise specified)


SWITCHING TIME vs.
LOAD RESISTANCE


CURRENT TRANSFER RATIO vs. FORWARD CURRENT


NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE


SWITCHING TIME vs.
LOAD RESISTANCE


FREQUENCY RESPONSE


Remark The graphs indicate nominal characteristics.

## TAPING SPECIFICATIONS (UNIT: mm)

Tape Direction


Outline and Dimensions (Tape)


Outline and Dimensions (Reel)


Packing: $3500 \mathrm{pcs} /$ reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)


Remark
All dimensions in this figure must be evaluated before use.

## NOTES ON HANDLING

1. Recommended soldering conditions
(1) Infrared reflow soldering

- Peak reflow temperature $260^{\circ} \mathrm{C}$ or below (package surface temperature)
- Time of peak reflow temperature
- Time of temperature higher than $220^{\circ} \mathrm{C}$ 10 seconds or less
60 seconds or less
- Time to preheat temperature from 120 to $180^{\circ} \mathrm{C} \quad 120 \pm 30 \mathrm{~s}$
- Number of reflows

Three

- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of $0.2 \mathrm{Wt} \%$ is recommended.)

Recommended Temperature Profile of Infrared Reflow

(2) Wave soldering

- Temperature $260^{\circ} \mathrm{C}$ or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions $120^{\circ} \mathrm{C}$ or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of $0.2 \mathrm{Wt} \%$ is recommended.)
(3) Soldering by Soldering Iron
- Peak Temperature (lead part temperature) $350^{\circ} \mathrm{C}$ or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine
(The flux with a maximum chlorine content of $0.2 \mathrm{Wt} \%$ is recommended.)
(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
(b) Please be sure that the temperature of the package would not be heated over $100^{\circ} \mathrm{C}$
(4) Cautions
- Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

- Do not use fixing agents or coatings containing halogen-based substances.


## 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.
3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

## USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter | Symbol | Rating | Unit |
| :---: | :---: | :---: | :---: |
| Climatic test class (IEC 60068-1/DIN EN 60068-1) |  | 40/115/21 |  |
| Dielectric strength <br> maximum operating isolation voltage <br> Test voltage (partial discharge test, procedure a for type test and random test) $\mathrm{U}_{\mathrm{pr}}=1.6 \times \mathrm{U}_{\mathrm{IORm}}, \mathrm{Pd}_{\mathrm{d}}<5 \mathrm{pC}$ | UIorm Upr | $\begin{aligned} & 1100 \\ & 1760 \end{aligned}$ | $\bigvee_{\text {peak }}$ <br> $V_{\text {peak }}$ |
| Test voltage (partial discharge test, procedure $b$ for all devices) $U_{\text {pr }}=1.875 \times$ UוORм, $\mathrm{P}_{\mathrm{d}}<5 \mathrm{pC}$ | $\mathrm{U}_{\mathrm{pr}}$ | 2063 | $V_{\text {peak }}$ |
| Highest permissible overvoltage | Uוотм | 8000 | $V_{\text {peak }}$ |
| Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)) |  | 2 |  |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11)) | CTI | 400 |  |
| Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)) |  | II |  |
| Storage temperature range | $\mathrm{T}_{\text {stg }}$ | $-40 \sim+125$ | ${ }^{\circ} \mathrm{C}$ |
| Operating temperature range | $\mathrm{T}_{\mathrm{A}}$ | $-40 \sim+115$ | ${ }^{\circ} \mathrm{C}$ |
| Isolation resistance, minimum value $\begin{aligned} & V_{10}=500 \mathrm{~V} \text { dc at } T_{A}=25^{\circ} \mathrm{C} \\ & V_{10}=500 \mathrm{~V} \text { dc at } T_{A} \text { MAX. at least } 100^{\circ} \mathrm{C} \end{aligned}$ | Ris MIN. Ris MIN. | $\begin{aligned} & 10^{12} \\ & 10^{11} \end{aligned}$ | $\begin{aligned} & \Omega \\ & \Omega \end{aligned}$ |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) <br> Package temperature <br> Current (input current $\mathrm{I}_{\mathrm{F}}, \mathrm{Psi}=0$ ) <br> Power (output or total power dissipation) <br> Isolation resistance $\mathrm{V}_{10}=500 \mathrm{~V}$ dc at $\mathrm{T}_{\mathrm{A}}=\mathrm{Tsi}$ | Tsi <br> Isi <br> Psi <br> Ris MIN. | $\begin{gathered} 175 \\ 400 \\ 700 \\ 10^{9} \end{gathered}$ | $\begin{gathered} { }^{\circ} \mathrm{C} \\ \mathrm{~mA} \\ \mathrm{~mW} \\ \Omega \end{gathered}$ |

## Method a) Destructive Test, Type and Sample Test



$$
\begin{aligned}
& t_{1}, \mathrm{t}_{2}=1 \mathrm{to} 10 \mathrm{sec} \\
& \mathrm{t}_{3} \mathrm{t}_{4}=1 \mathrm{sec} \\
& \mathrm{t}_{\mathrm{m} \text { (PARTIAL }} \\
& \mathrm{t}_{\text {IISCHARGE })}=10 \mathrm{sec} \\
& \mathrm{t}_{\mathrm{ini}}=60 \mathrm{sec} \\
& \hline
\end{aligned}
$$

Method b) Non-destructive Test, 100\% Production Test


$$
\begin{aligned}
& \mathrm{t}_{3}, \mathrm{t}_{4}=0.1 \mathrm{sec} \\
& \mathrm{t}_{\mathrm{p} \text { (PARTIAL DISCHARGE) }}=1.0 \mathrm{sec} \\
& \mathrm{t}_{\text {test }}=1.2 \mathrm{sec}
\end{aligned}
$$

| Caution GaAs Products | This product uses gallium arsenide (GaAs). <br> GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe <br> the following points. <br> - Follow related laws and ordinances when disposing of the product. If there are no applicable laws <br> and/or ordinances, dispose of the product as recommended below. <br> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of <br> materials that contain arsenic and other such industrial waste materials. <br> 2. Exclude the product from general industrial waste and household garbage, and ensure that the <br> product is controlled (as industrial waste subject to special control) up until final disposal. <br> - Do not burn, destroy, cut, crush, or chemically dissolve the product. |
| :---: | :--- | :--- |
| - Do not lick the product or in any way allow it to enter the mouth. |  |

